

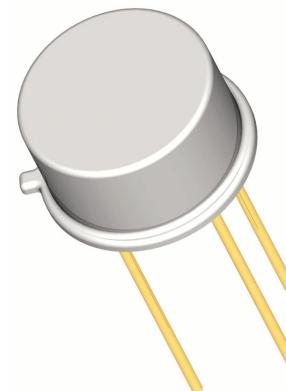
**Description**

Semicoa Semiconductors offers:

- Screening and processing per MIL-PRF-19500 Appendix E
- JAN level (2N5151LJ)
- JANTX level (2N5151LJX)
- JANTXV level (2N5151LJV)
- JANS level (2N5151LJS)
- QCI to the applicable level
- 100% die visual inspection per MIL-STD-750 method 2072 for JANTXV and JANS
- Radiation testing (total dose) upon request

**Applications**

- High-speed power switching
- Low power
- PNP silicon transistor

**Features**

- Hermetically sealed TO-5 metal can
- Also available in chip configuration
- Chip geometry 9702
- Reference document: MIL-PRF-19500/545

**Benefits**

- Qualification Levels: JAN, JANTX, JANTXV and JANS
- Radiation testing available

<b>Absolute Maximum Ratings</b>		$T_c = 25^\circ\text{C}$ unless otherwise specified	
<b>Parameter</b>	<b>Symbol</b>	<b>Rating</b>	<b>Unit</b>
Collector-Emitter Voltage	$V_{CEO}$	80	Volts
Collector-Base Voltage	$V_{CBO}$	100	Volts
Emitter-Base Voltage	$V_{EBO}$	5.5	Volts
Collector Current, Continuous	$I_C$	2	A
Power Dissipation, $T_A = 25^\circ\text{C}$ Derate linearly above $25^\circ\text{C}$	$P_T$	1 5.7	W mW/ $^\circ\text{C}$
Power Dissipation, $T_c = 25^\circ\text{C}$ Derate linearly above $25^\circ\text{C}$	$P_T$	11.8 66.7	W mW/ $^\circ\text{C}$
Thermal Resistance	$R_{QJA}$ $R_{QJC}$	175 15	$^\circ\text{C}/\text{W}$
Operating Junction Temperature Storage Temperature	$T_J$ $T_{STG}$	-65 to +200	$^\circ\text{C}$

## ELECTRICAL CHARACTERISTICS

characteristics specified at  $T_A = 25^\circ\text{C}$ 

## Off Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Collector-Emitter Breakdown Voltage	$V_{(\text{BR})\text{CEO}}$	$I_C = 100 \text{ mA}$	80			Volts
Collector-Emitter Cutoff Current	$I_{\text{CES}1}$	$V_{\text{CE}} = 60 \text{ Volts}$			1	$\mu\text{A}$
Collector-Emitter Cutoff Current	$I_{\text{CES}2}$	$V_{\text{CE}} = 100 \text{ Volts}$			1	mA
Collector-Emitter Cutoff Current	$I_{\text{CEO}}$	$V_{\text{CE}} = 40 \text{ Volts}$			50	$\mu\text{A}$
Collector-Emitter Cutoff Current	$I_{\text{CEX}}$	$V_{\text{CE}} = 60 \text{ Volts}, V_{\text{EB}} = 2 \text{ Volts}, T_A = 150^\circ\text{C}$			500	nA
Emitter-Base Cutoff Current	$I_{\text{EBO}1}$	$V_{\text{EB}} = 4 \text{ Volts}$			1	$\mu\text{A}$
Emitter-Base Cutoff Current	$I_{\text{EBO}1}$	$V_{\text{EB}} = 5.5 \text{ Volts}$			1	mA

## On Characteristics

Pulse Test: Pulse Width = 300  $\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ 

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
DC Current Gain	$h_{\text{FE}1}$	$I_C = 50 \text{ mA}, V_{\text{CE}} = 5 \text{ Volts}$	20			
	$h_{\text{FE}2}$	$I_C = 2.5 \text{ A}, V_{\text{CE}} = 5 \text{ Volts}$	30		90	
	$h_{\text{FE}3}$	$I_C = 5 \text{ A}, V_{\text{CE}} = 5 \text{ Volts}$	20			
	$h_{\text{FE}4}$	$I_C = 2.5 \text{ A}, V_{\text{CE}} = 5 \text{ Volts}, T_A = -55^\circ\text{C}$	15			
Base-Emitter Voltage	$V_{\text{BE}}$	$V_{\text{CE}} = 5 \text{ Volts}, I_C = 2.5 \text{ mA}$			1.45	Volts
Base-Emitter Saturation Voltage	$V_{\text{BEsat}1}$	$I_C = 2.5 \text{ A}, I_B = 250 \text{ mA}$			1.45	Volts
	$V_{\text{BEsat}2}$	$I_C = 5 \text{ A}, I_B = 500 \text{ mA}$			2.20	Volts
Collector-Emitter Saturation Voltage	$V_{\text{CEsat}1}$	$I_C = 2.5 \text{ A}, I_B = 250 \text{ mA}$			0.75	Volts
	$V_{\text{CEsat}2}$	$I_C = 5 \text{ A}, I_B = 500 \text{ mA}$			1.50	Volts

## Dynamic Characteristics

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Magnitude – Common Emitter, Short Circuit Forward Current Transfer Ratio	$ h_{\text{FE}} $	$V_{\text{CE}} = 5 \text{ Volts}, I_C = 500 \text{ mA}, f = 10 \text{ MHz}$	6			
Small Signal Short Circuit Forward Current Transfer Ratio	$h_{\text{FE}}$	$V_{\text{CE}} = 5 \text{ Volts}, I_C = 100 \text{ mA}, f = 1 \text{ kHz}$	20			
Open Circuit Output Capacitance	$C_{\text{OBO}}$	$V_{\text{CB}} = 10 \text{ Volts}, I_E = 0 \text{ mA}, f = 1 \text{ MHz}$			250	pF

## Switching Characteristics

Saturated Turn-On Time Storage Time Fall Time Saturated Turn-Off Time	$t_{\text{ON}}$ $t_s$ $t_f$ $t_{\text{OFF}}$	$I_C = 5 \text{ A}, I_{B1} = 500 \text{ mA}, I_{B2} = -500 \text{ mA}, V_{\text{BEoff}} = 3.7 \text{ V}, R_L = 6 \Omega$			0.5 1.4 0.5 1.5	$\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$ $\mu\text{s}$
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